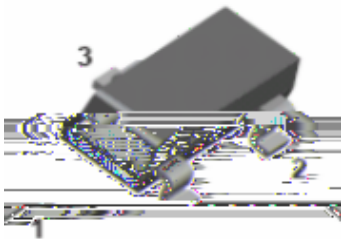


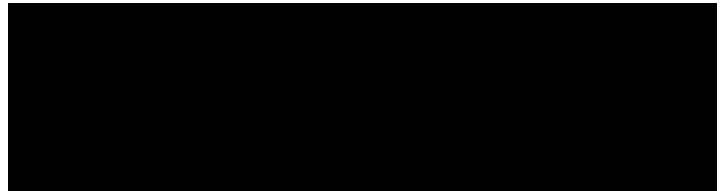
Moisture sensitivity level 1  
Reverse voltage 80V  
Aver



Signal switching  
High frequency rectifier

T-23

SO<sup>8</sup>



( $T_a=25$  Unless otherwise specified)

|                                 |           |   |                                 |
|---------------------------------|-----------|---|---------------------------------|
| Device marking code             |           |   | BA1                             |
| Repetitive peak reverse voltage | $V_{RRM}$ | V | urrent @ t=8.3ms half-sine wave |

|                                                               |           |    |             |
|---------------------------------------------------------------|-----------|----|-------------|
|                                                               |           |    | 1           |
| Non-repetitive Surge peak forward current @ t=1ms square wave | $I_{FSM}$ | A  | 1           |
| Power dissipation                                             | $P_D$     | mW | 200         |
| Junction temperature                                          | $T_J$     |    | -55 to +150 |
| Storage temperature                                           | $T_{STG}$ |    | -55 to +150 |



# DAN217

RoHS  
COMPLIANT

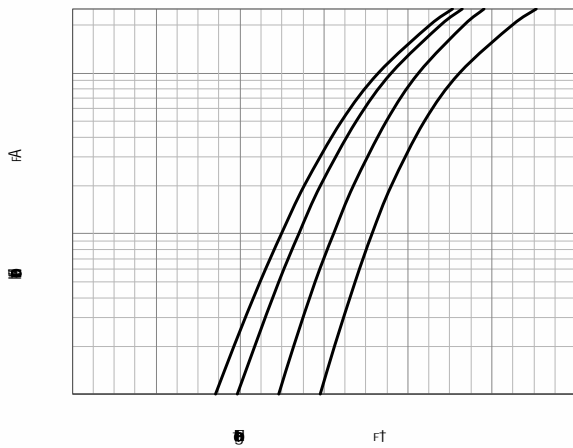
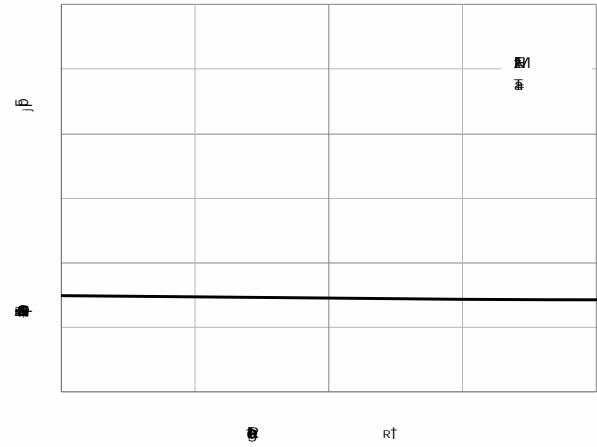
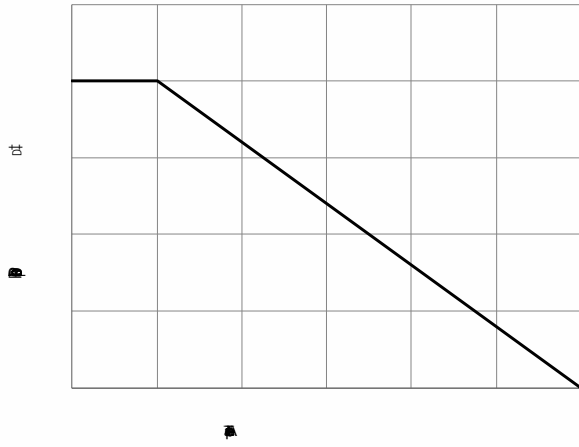
( $T_a=25$  Unless otherwise specified)

| Reverse voltage         | $V_R$    | V       | $I_R=100\mu A$                                | 80 |  |     |
|-------------------------|----------|---------|-----------------------------------------------|----|--|-----|
| Forward voltage         | $V_F$    | V       | $I_F=100mA$                                   |    |  | 1.2 |
| Reverse leakage current | $I_R$    | $\mu A$ | $V_R=70V$                                     |    |  | 0.1 |
| Junction capacitance    | $C_j$    | pF      | $V_R=0V, f=1MHz$                              |    |  | 2   |
| Reverse recovery time   | $T_{rr}$ | ns      | $I_F=I_R=10mA$ $I_{rr}=0.1*I_R,$<br>$R_L=100$ |    |  | 4   |

| Thermal resistance, junction-to-ambient | $R_{J-A}^{(1)}$ | /W | 625 |
|-----------------------------------------|-----------------|----|-----|
| Thermal resistance, junction-to-case    | $R_{J-C}^{(1)}$ | /W | 500 |

## Note:

- 1 Device mounted on PCB, single-sided copper with standard footprint







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